SWITCHMODE Power Rectifier

D²PAK Surface Mount Power Package

The D²PAK Power Rectifier is a state-of-the-art device that employs the Schottky Barrier principle with a platinum barrier metal.

Features

- Center-Tap Configuration
- Guardring for Stress Protection
- Low Forward Voltage
- 175°C Operating Junction Temperature
- Epoxy Meets UL 94 V-0 @ 0.125 in
- Short Heat Sink Tab Manufactured Not Sheared
- Similar in Size to the Industry Standard TO-220 Package
- AEC-Q101 Qualified and PPAP Capable
- SBRB Prefix for Automotive and Other Applications Requiring Unique Site and Control Change Requirements
- All Packages are Pb-Free*

Mechanical Characteristics

- Case: Epoxy, Molded, Epoxy Meets UL 94 V-0
- Weight: 1.7 Grams (Approximately)
- Finish: All External Surfaces Corrosion Resistant and Terminal Leads are Readily Solderable
- Lead and Mounting Surface Temperature for Soldering Purposes: 260°C Max. for 10 Seconds
- Device Meets MSL1 Requirements
- ESD Ratings:
 - Machine Model = C (> 400 V)
 - ♦ Human Body Model = 3B (> 8000 V)



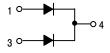
ON Semiconductor®

http://onsemi.com

SCHOTTKY BARRIER RECTIFIER 30 AMPERES, 45 VOLTS



D²PAK CASE 418B STYLE 3



MARKING DIAGRAM



A = Assembly Location

Y = Year
WW = Work Week
B2545 = Device Code
G = Pb-Free Package
AKA = Diode Polarity

ORDERING INFORMATION

See detailed ordering and shipping information in the package dimensions section on page 2 of this data sheet.

^{*}For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

MAXIMUM RATINGS (Per Leg)

Rating	Symbol	Value	Unit
Peak Repetitive Reverse Voltage Working Peak Reverse Voltage DC Blocking Voltage	V _{RRM} V _{RWM} V _R	45	V
Average Rectified Forward Current (Rated V _R , T _C = 164°C) Total Device	I _{F(AV)}	15 30	А
Peak Repetitive Forward Current (Rated V _R , Square Wave, 20 kHz, T _C = 160°C)	I _{FRM}	30	А
Non-Repetitive Peak Surge Current (Surge Applied at Rated Load Conditions Halfwave, Single Phase, 60 Hz)	I _{FSM}	150	А
Peak Repetitive Reverse Surge Current (2.0 μs, 1.0 kHz)	I _{RRM}	1.0	Α
Storage Temperature Range	T _{stg}	-65 to +175	°C
Operating Junction Temperature (Note 1)	TJ	-65 to +175	°C
Voltage Rate of Change (Rated V _R)	dv/dt	10,000	V/μs

Stresses exceeding Maximum Ratings may damage the device. Maximum Ratings are stress ratings only. Functional operation above the Recommended Operating Conditions is not implied. Extended exposure to stresses above the Recommended Operating Conditions may affect device reliability.

THERMAL CHARACTERISTICS (Per Leg)

Characteristic	Symbol	Value	Unit
Thermal Resistance,			°C/W
Junction-to-Case	$R_{ heta JC}$	1.5	
Junction-to-Ambient (Note 2)	$R_{\theta JA}$	50	

^{2.} When mounted using minimum recommended pad size on FR-4 board.

ELECTRICAL CHARACTERISTICS (Per Diode)

Symbol	Characteristic	Condition	Min	Тур	Max	Unit
V _F	Instantaneous Forward Voltage (Note 3)	I _F = 15 Amp, T _J = 25°C I _F = 15 Amp, T _J = 125°C I _F = 30 Amp, T _J = 25°C I _F = 30 Amp, T _J = 125°C	- - -	- 0.50 - 0.65	0.62 0.57 0.82 0.72	V
I _R	Instantaneous Reverse Current (Note 3)	V_R = 45 Volts, T_J = 25°C V_R = 45 Volts, T_J = 125°C	-	9.0	0.2 25	mA

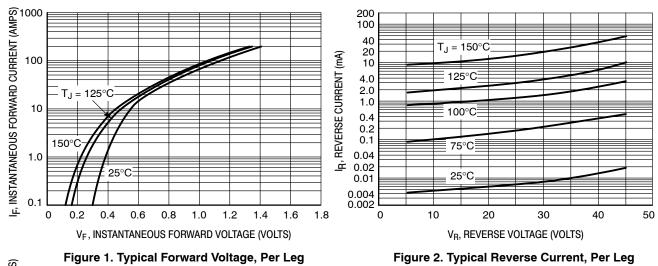
^{3.} Pulse Test: Pulse Width = 300 μ s, Duty Cycle \leq 2.0%.

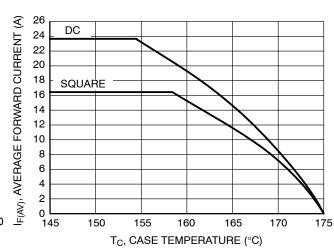
ORDERING INFORMATION

Device	Package	Shipping [†]
MBRB2545CTG	D ² PAK (Pb-Free)	50 Units / Rail
SBRB2545CTG	D ² PAK (Pb-Free)	50 Units / Rail
MBRB2545CTT4G	D ² PAK (Pb-Free)	800 Units / Tape & Reel
SBRB2545CTT4G	D ² PAK (Pb-Free)	800 Units / Tape & Reel

[†]For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

^{1.} The heat generated must be less than the thermal conductivity from Junction-to-Ambient: $dP_D/dT_J < 1/R_{\theta JA}$.





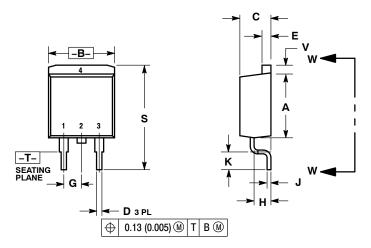
PF(AV), AVERAGE FORWARD POWER DISSIPATION (WATTS) 32 **SQUARE WAVE** 28 T_J = 125°C $\frac{I_{PK}}{I_{AV}}$ (RESISTIVE LOAD) 24 DC 20 (CAPACITIVE 16 LOADS) 10 12 I_{PK} I_{AV} 8 16 20 24 28 IF, AVERAGE FORWARD CURRENT (AMPS)

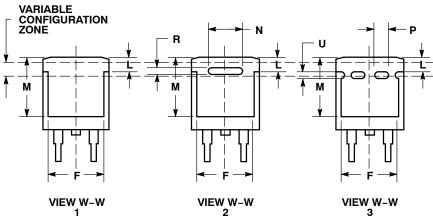
Figure 3. Typical Forward Power Dissipation

Figure 4. Current Derating, Case per Leg

PACKAGE DIMENSIONS

D²PAK 3 CASE 418B-04 ISSUE K



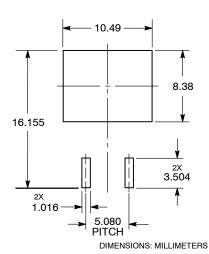


- NOTES:
 1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
 2. CONTROLLING DIMENSION: INCH.
 3. 418B-01 THRU 418B-03 OBSOLETE, NEW STANDARD 418B-04.

	INCHES		MILLIN	IETERS
DIM	MIN	MAX	MIN	MAX
Α	0.340	0.380	8.64	9.65
В	0.380	0.405	9.65	10.29
С	0.160	0.190	4.06	4.83
D	0.020	0.035	0.51	0.89
E	0.045	0.055	1.14	1.40
F	0.310	0.350	7.87	8.89
G	0.100 BSC		2.54 BSC	
Н	0.080	0.110	2.03	2.79
J	0.018	0.025	0.46	0.64
K	0.090	0.110	2.29	2.79
L	0.052	0.072	1.32	1.83
М	0.280	0.320	7.11	8.13
N	0.197 REF		5.00 REF	
P	0.079 REF		2.00 REF	
R	0.039 REF		0.99 REF	
S	0.575	0.625	14.60	15.88
V	0.045	0.055	1.14	1.40

- STYLE 3: PIN 1. ANODE 2. CATHODE 3. ANODE 4. CATHODE

SOLDERING FOOTPRINT*



*For additional information on our Pb–Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

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